

# TRANSISTOR MODULE

# QCA75AA100



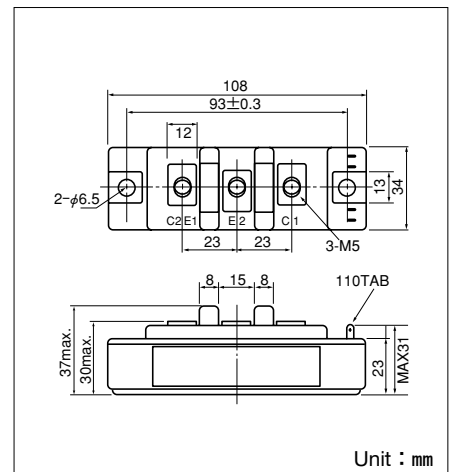
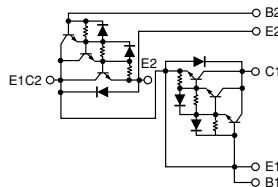
UL;E76102 (M)

QCA75AA100 is a dual Darlington power transistor module which has series-connected high speed, high power Darlington transistors. Each transistor has a reverse paralleled fast recovery diode. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction,

- $I_C=75A$ ,  $V_{CEX}=1000V$
- Low saturation voltage for higher efficiency.
- High DC current gain  $h_{FE}$
- Isolated mounting base

### (Applications)

Motor Control (VVVF), AC/DC Servo, UPS, Switching Power Supply, Ultrasonic Application



### Maximum Ratings

( $T_j=25^\circ\text{C}$  unless otherwise specified)

Symbol	Item	Conditions	Ratings		Unit
			QCA75AA100		
$V_{CBO}$	Collector-Base Voltage		1000		V
$V_{CEX}$	Collector-Emitter Voltage	$V_{BE}=-2V$	1000		V
$V_{EBO}$	Emitter-Base Voltage		7		V
$I_C$	Collector Current		75		A
$-I_C$	Reverse Collector Current		75		A
$I_B$	Base Current		4		A
$P_T$	Total power dissipation	$T_C=25^\circ\text{C}$	500		W
$T_j$	Junction Temperature		-40 to +150		$^\circ\text{C}$
$T_{stg}$	Storage Temperature		-40 to +125		$^\circ\text{C}$
$V_{ISO}$	Isolation Voltage	A.C.1minute	2500		V
	Mounting Torque	Mounting (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	N·m kgf·cm
		Terminal (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	
	Mass	Typical Value	250		g

### Electrical Characteristics

Symbol	Item	Conditions	Ratings		Unit
			Min.	Max.	
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=1000V$		1.0	mA
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=7V$		200	mA
$V_{CEX(SUS)}$	Collector Emitter Sustaining Voltage	$I_C=15A$ , $I_{B2}=-4A$	1000		V
$h_{FE}$	DC Current Gain	$I_C=75A$ , $V_{CE}=2.8V$	75		
		$I_C=75A$ , $V_{CE}=5V$	100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=75A$ , $I_B=1.5A$		2.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=75A$ , $I_B=1.5A$		3.5	V
$t_{on}$	Switching Time	On Time		2.5	$\mu\text{s}$
$t_s$		Storage Time	$V_{CC}=600V$ , $I_C=75A$ $I_{B1}=1.5A$ , $I_{B2}=-1.5A$	15.0	
$t_f$		Fall Time		3.0	
$V_{ECO}$	Collector-Emitter Reverse Voltage	$-I_C=75A$		1.8	V
$R_{th(j-c)}$	Thermal Impedance (junction to case)	Transistor part		0.25	$^\circ\text{C/W}$
		Diode part		1.20	

